

Supporting information for

Enhancing oxide-ionic conductivity of $\text{Ba}_3\text{Mo}_{1+x}\text{Nb}_{1-2x}\text{Ge}_x\text{O}_{8.5}$ at intermediate temperatures: the effect of site-selective Ge^{4+} -substitution

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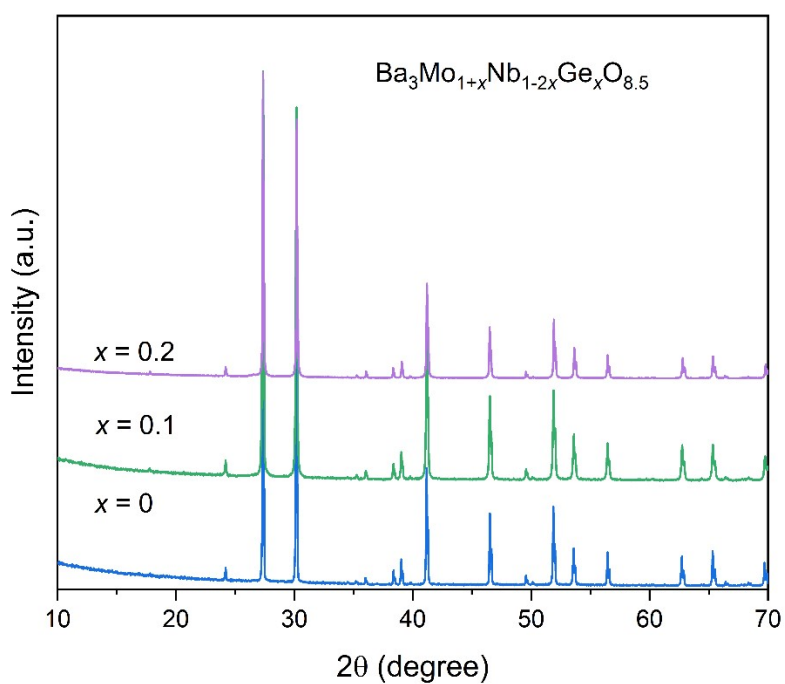


Figure S1. Powder X-ray diffraction patterns of $\text{Ba}_3\text{Mo}_{1+x}\text{Nb}_{1-2x}\text{Ge}_x\text{O}_{8.5}$ ($x \leq 0.2$)

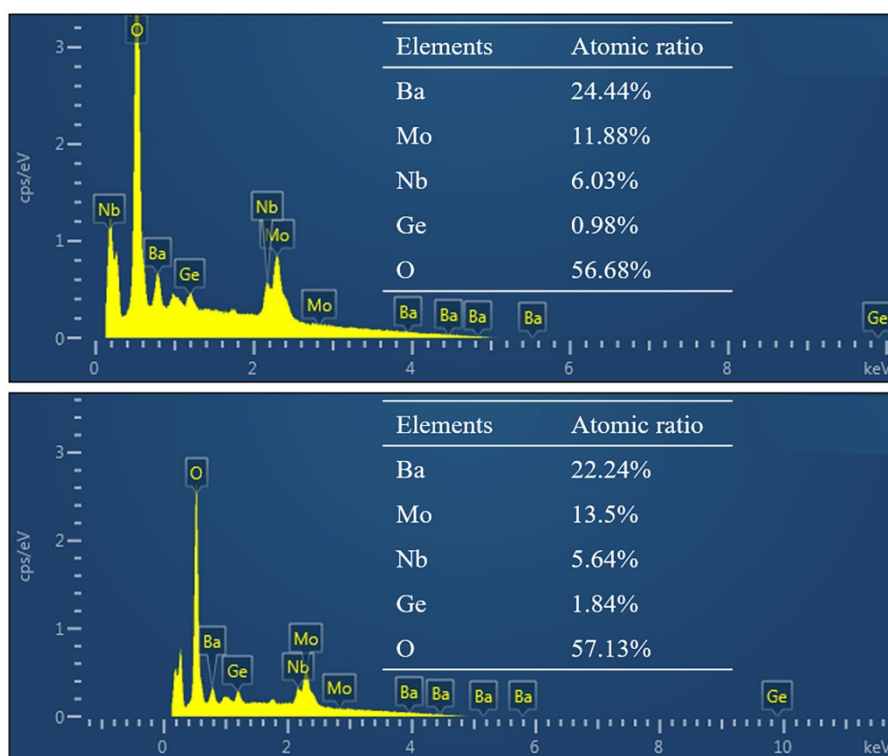


Figure S2. The Energy Dispersive X-ray (EDX) spectra for $\text{Ba}_3\text{Mo}_{1.2}\text{Nb}_{0.6}\text{Ge}_{0.2}\text{O}_{8.5}$ recorded on two particles. The insets show the detected atomic ratios.

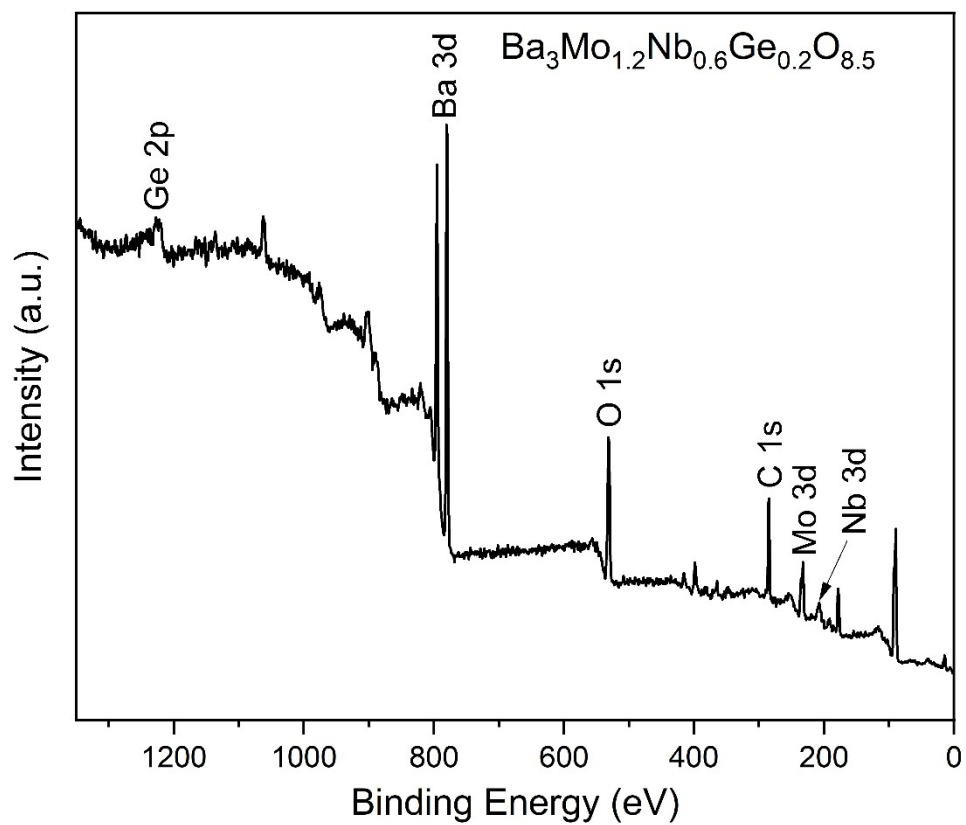


Figure S3. The survey XPS of $\text{Ba}_3\text{Mo}_{1.2}\text{Nb}_{0.6}\text{Ge}_{0.2}\text{O}_{8.5}$.

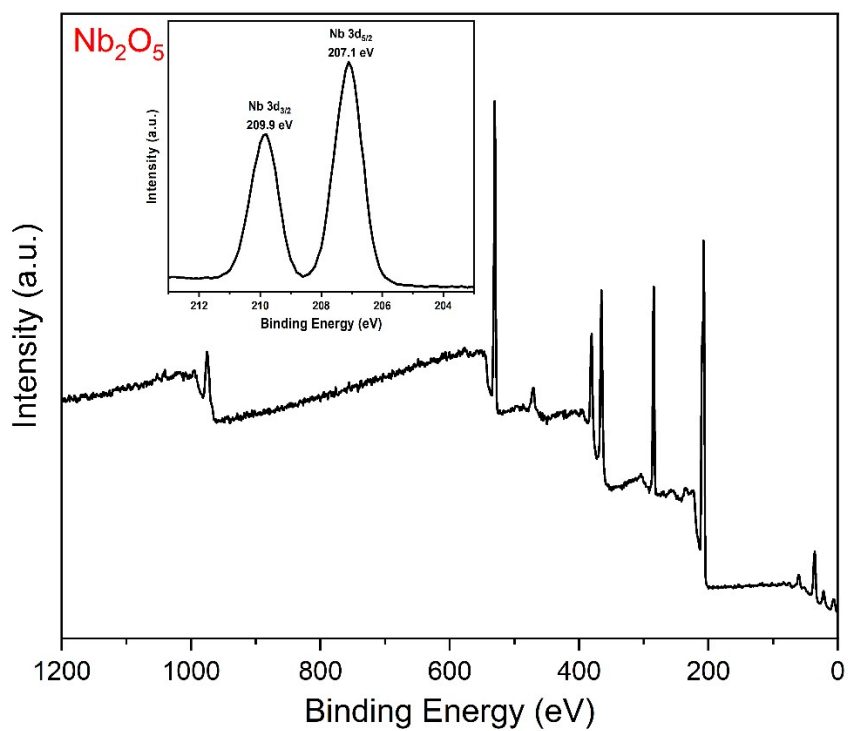
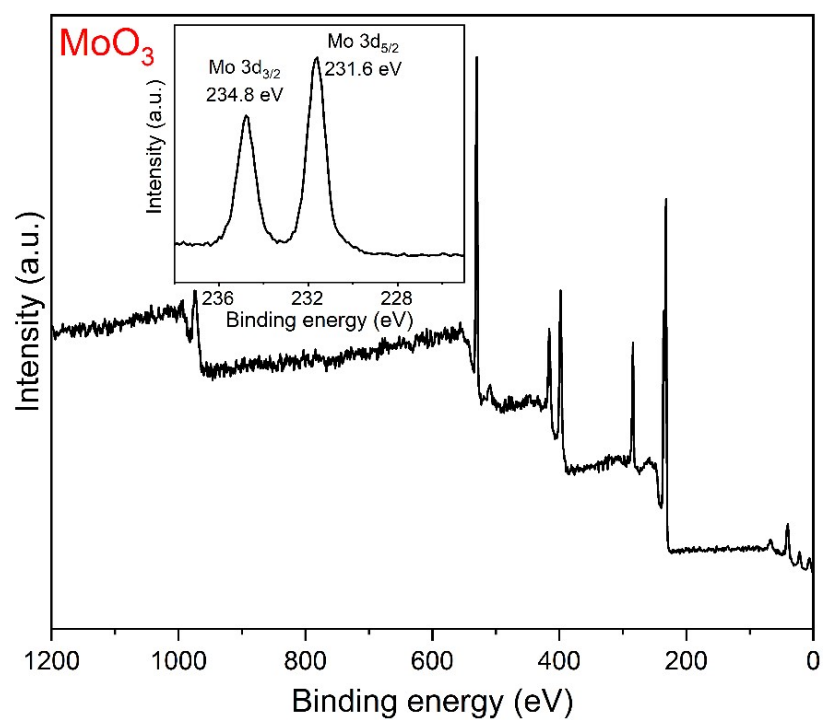


Figure S4. The survey XPS of MoO₃ and Nb₂O₅. The inset shows the Mo 3d and Nb 3d signals.

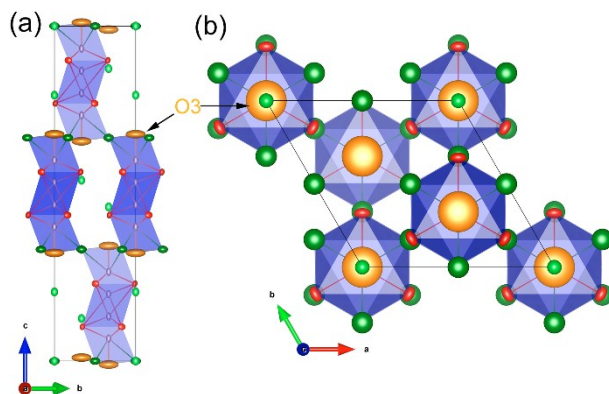


Figure S5. Crystal structure of $\text{Ba}_3\text{Mo}_{1.2}\text{Nb}_{0.6}\text{Ge}_{0.2}\text{O}_{8.5}$ with atomic displacement ellipsoids drawn at 50% probability.

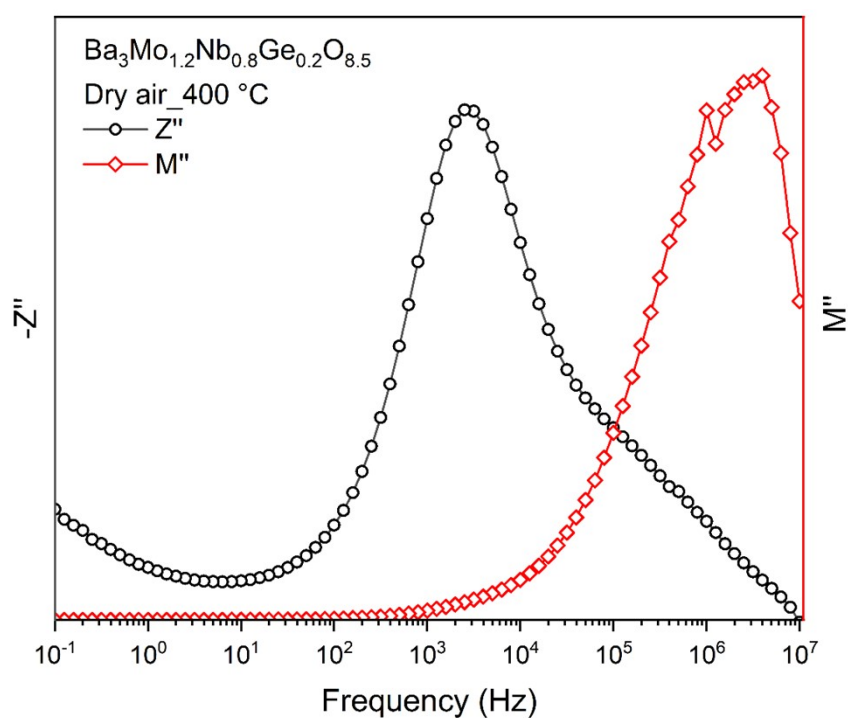


Figure S6. Plots of the imaginary part of the impedance (Z'') and electrical modulus (M'') along with frequency.

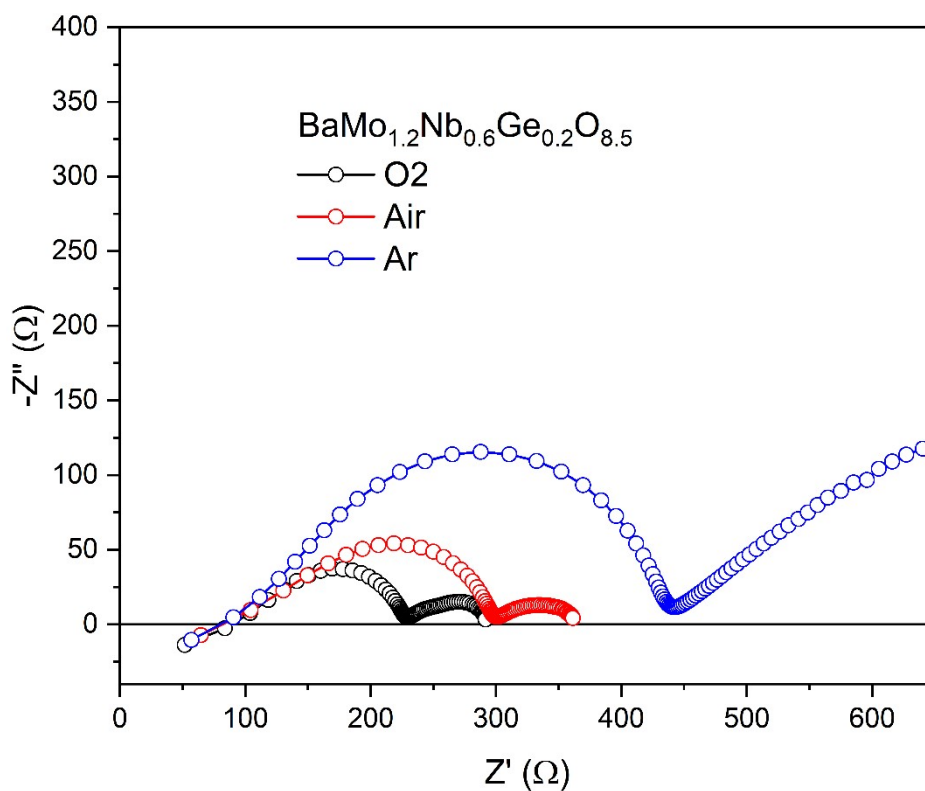


Figure S7. Complex impedance plots of $\text{Ba}_3\text{Mo}_{1.2}\text{Nb}_{0.6}\text{Ge}_{0.2}\text{O}_{8.5}$ recorded in dry air, O_2 , and Ar atmospheres at $550\text{ }^\circ\text{C}$.

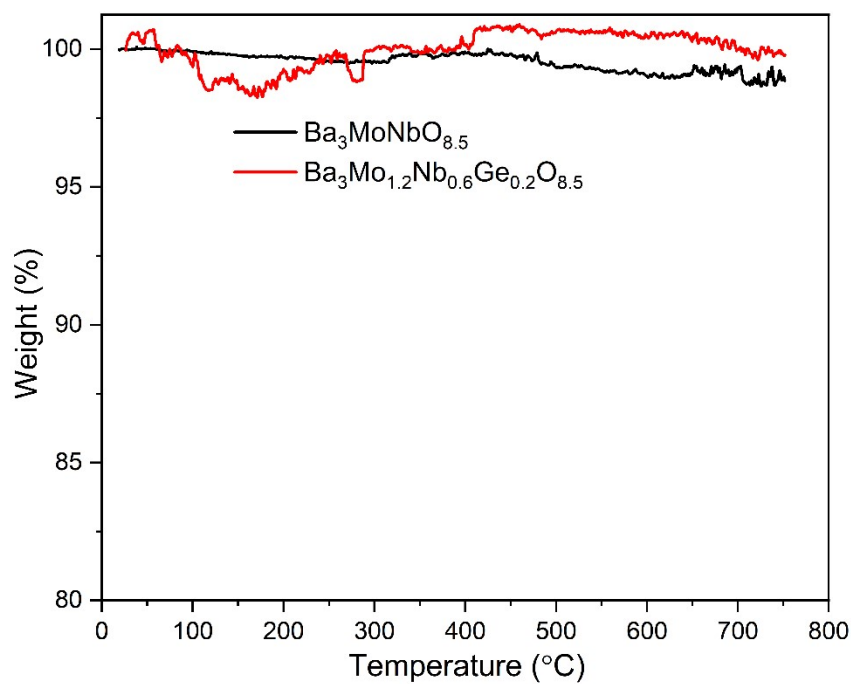


Figure S8. TGA curves for $\text{Ba}_3\text{Mo}_{1+x}\text{Nb}_{1-2x}\text{Ge}_x\text{O}_{8.5}$ with $x = 0$ and 0.2 measured under air atmospheres.

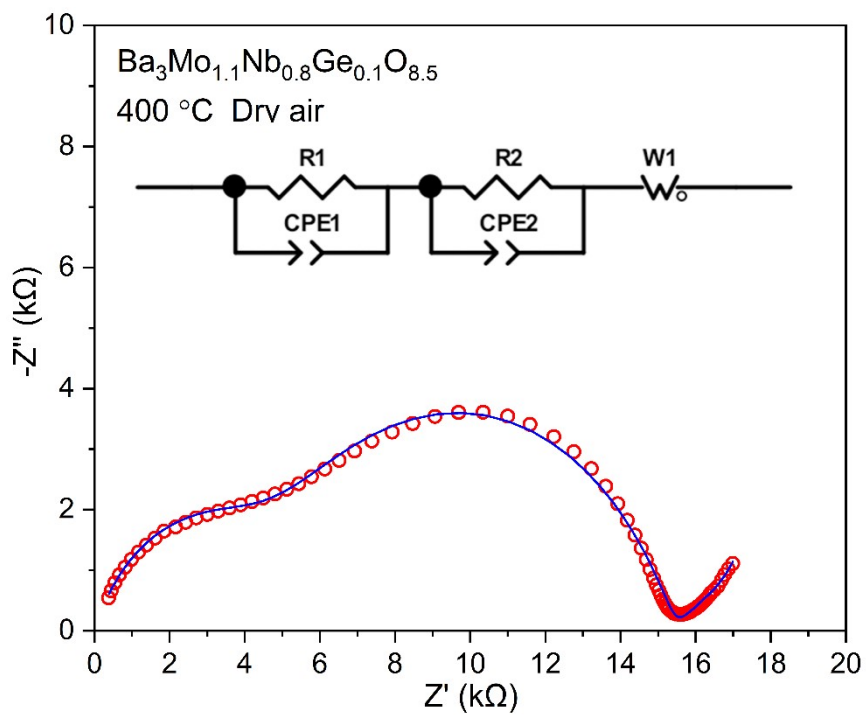


Figure S9. An impedance spectrum fit for $\text{Ba}_3\text{Mo}_{1.1}\text{Nb}_{0.8}\text{Ge}_{0.1}\text{O}_{8.5}$. The inset shows the equivalent circuit, where R, CPE, and W represent the resistor, constant phase element, and electrode response.

Table S1. The atomic coordinates, occupancies, anisotropic thermal displacement parameters, bond valence sums for $\text{Ba}_3\text{Mo}_{1.4}\text{Nb}_{0.6}\text{Ge}_{0.2}\text{O}_{8.5}$ obtained from Rietveld refinement against neutron powder diffraction data.^a

Site	Ba1	Ba2	Mo1/Nb1/Ge1	Mo2/Nb2	O1	O2	O3
<i>x</i>	0	0	0	0	0.17196(2)	0	0.0836(4)
<i>y</i>	0	0	0	0	0.34392(2)	0.5	0.0097(8)
<i>z</i>	0	0.2063(1)	0.40052(5)	0.4716(9)	0.1025(5)	0	0.3231(2)
BVS	2.06	2.00	5.54/5.00/3.60	4.33/4.16	-1.97	-1.39	-2.23
			0.5773(8)				
				0.0247(8)			
Occ.	1	1	0.2877(4)		1	0.408(2)	0.1063(6)
				0.0123(4)			
			0.1				
U_{11} (Å ²)	0.0232(2)	0.0232(2)	0.0140(2)	0.0094(4)	0.0249(6)	0.0468(2)	0.033(2)
U_{22} (Å ²)	0.0232(2)	0.0232(2)	0.0140(2)	0.0094(4)	0.0138(1)	0.0468(2)	
U_{33} (Å ²)	0.0306(7)	0.0306(7)	0.0314(9)	0.0273(7)	0.0186(9)	0.013(3)	
U_{12} (Å ²)	0.0116(3)	0.0116(3)	0.0070(3)	0.0047(2)	0.0069(6)	0.0234(9)	
U_{13} (Å ²)	0	0	0	0	0.0021(3)	0	
U_{23} (Å ²)	0	0	0	0	0.0010(2)	0	

^aThe thermal factor of O3 was refined with a single *U* factor; For for O2 and the cations, $U_{11} = U_{22} = 2U_{12}$, $U_{13} = U_{23} = 0$; For O1, $U_{22} = 2U_{12}$, $U_{23} = 2U_{13}$.

Table S2. Selected interatomic distances in Ba₃Mo_{1.4}Nb_{0.6}Ge_{0.2}O_{8.5}.

Bond	Length (Å)	Bond	Length (Å)
M1/Ge-O3	1.699(4)	Ba1-O1 × 6	2.7902(8)
M1/Ge-O1 × 3	1.8143(8)	Ba1-O2 × 6	2.9556(4)
M1/Ge-O2 × 3	2.2189(9)	Ba2-O3	2.520(4)
M2-O1 × 3	1.805(8)	Ba2-O1 × 3	2.801(2)
M2-O1 × 3	2.58(2)	Ba2-O1 × 6	3.0036(4)